

SGM8773 High Voltage, High Precision, Push-Pull, Dual Differential Comparator

GENERAL DESCRIPTION

The SGM8773 is a dual, high precision differential voltage comparator optimized for high voltage operation. The device can operate from 2.8V to 36V single supply or from ± 1.4 V to ± 18 V dual power supplies. It consumes low supply current without being affected by the supply voltage. Input common mode voltage is 1.5V lower than ± 1.4 V s. The SGM8773 has a push-pull output structure without external pull-up resistors. This feature makes it a good choice for applications whose PCB sizes are limited.

The SGM8773 is available in Green SOIC-8 and TDFN-3×3-8L packages. The SGM8773 is specified over the extended -40°C to +125°C temperature range.

FEATURES

Wide Supply Ranges
 Single Supply: 2.8V to 36V
 Dual Supplies: ±1.4V to ±18V

• Low Supply Current: 330µA (TYP)

Low Input Offset Voltage: 2.4mV (MAX)
 Low Input Bias Current: ±20pA (TYP)

• Minimum Input Common Mode Voltage: -V_s

Maximum Differential Input Voltage: +36V/-36V

• Push-Pull Output Structure

• Low Output Saturation Voltage

• Supports CMOS or TTL Logic

-40°C to +125°C Operating Temperature Range

 Available in Green SOIC-8 and TDFN-3×3-8L Packages

APPLICATIONS

Power System Monitor
Medical Equipment
Industrial Application
Battery Management System



PACKAGE/ORDERING INFORMATION

MODEL	PACKAGE DESCRIPTION	SPECIFIED TEMPERATURE RANGE	ORDERING NUMBER	PACKAGE MARKING	PACKING OPTION
SGM8773	SOIC-8	-40°C to +125°C	SGM8773XS8G/TR	SGM 8773XS8 XXXXX	Tape and Reel, 4000
SGIMO773	TDFN-3×3-8L	-40°C to +125°C	SGM8773XTDB8G/TR	SGM 8773DB XXXXX	Tape and Reel, 4000

MARKING INFORMATION

NOTE: XXXXX = Date Code, Trace Code and Vendor Code.

XXXXX	
L	— Vendor Code
	— Trace Code
	— Date Code - Year

Green (RoHS & HSF): SG Micro Corp defines "Green" to mean Pb-Free (RoHS compatible) and free of halogen substances. If you have additional comments or questions, please contact your SGMICRO representative directly.

ABSOLUTE MAXIMUM RATINGS

Supply Voltage, +V _S to -V _S 40V	/
Differential Input Voltage, V _{ID} 40V	/
Input/Output Voltage Range (-Vs) - 0.3V to (+Vs) + 0.3V	/
Junction Temperature+150°C)
Storage Temperature Range65°C to +150°C)
Lead Temperature (Soldering, 10s)+260°C)
ESD Susceptibility	
HBM2500V	/
MM400V	/
CDM	/

RECOMMENDED OPERATING CONDITIONS

Operating Temperature Range.	40°C to +125°C
Power Supply Range	2.8V to 36V

OVERSTRESS CAUTION

Stresses beyond those listed in Absolute Maximum Ratings may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods

may affect reliability. Functional operation of the device at any conditions beyond those indicated in the Recommended Operating Conditions section is not implied.

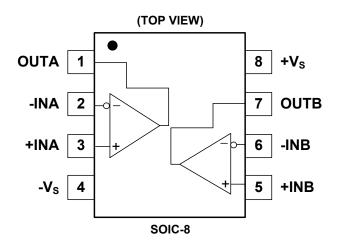
ESD SENSITIVITY CAUTION

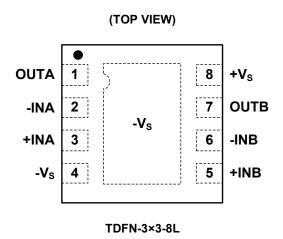
This integrated circuit can be damaged if ESD protections are not considered carefully. SGMICRO recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage. ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because even small parametric changes could cause the device not to meet the published specifications.

DISCLAIMER

SG Micro Corp reserves the right to make any change in circuit design, or specifications without prior notice.

PIN CONFIGURATIONS





ELECTRICAL CHARACTERISTICS

(At $T_A = +25^{\circ}C$, $V_S = \pm 1.4V$ to $\pm 18V$, Full = -40°C to +125°C, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	TEMP	MIN	TYP	MAX	UNITS
Input Offset Voltage	\/	\/ - 0\/	+25°C		0.6	2.4	mV
Imput Offset Voltage	Vos	$V_{CM} = 0V$	Full			2.8	IIIV
Input Bias Current	I _B	V _{CM} = 0V	+25°C		±20	±240	pА
Input Offset Current	Ios	V _{CM} = 0V	+25°C		±20	±320	pА
Maximum Differential Input Voltage	V _{ID}		Full			(+V _S) - (-V _S)	V
Maximum Input Difference Bias Current	11 1	$V_S = \pm 18V, V_{ID} = \pm 18V$	+25°C		2.2	3	
Maximum input Difference bias Current	I _{ID}	VS - ±10V, VID - ±10V	Full			5	μA
Input Common Mode Voltage Range (1)	V _{CM}		Full	-Vs		(+V _S) - 1.5	V
Common Mode Rejection Ratio	CMRR	$V_S = \pm 18V$, $V_{CM} = -V_S$ to $(+V_S) - 1.5V$	+25°C	96	116		- dB
Common wode Rejection Ratio			Full	80			
Power Supply Rejection Ratio	PSRR	V _S = 2.8V to 36V	+25°C	98	116		dB
Power Supply Rejection Ratio	PORK	V§ - 2.6V to 36V	Full	95			
	V _{OH}	I _{SOURCE} = 8mA, V _{ID} = 0.2V	+25°C		360	450	mV
Output Voltage Swing from Rail	∨он		Full			720	
Output voltage Swing from Ivali	V _{OL}	I _{SINK} = 8mA, V _{ID} = -0.2V	+25°C		200	280	
	VOL	ISINK - OITA, VID0.2V	Full			410	
Output Short-Circuit Current	I _{SOURCE}	$V_{OH} = (+V_S) - 1.5V, V_{ID} = 0.2V$	+25°C	21	25		mA
Output Short-Circuit Current	I _{SINK}	$V_{OL} = (-V_S) + 1.5V, V_{ID} = -0.2V$	+25°C	24	36		mA
Total Supply Current		I _{OUT} = 0mA	+25°C		330	400	
тотат Зарргу Сапені	Is	IOUT - UITIA	Full			450	μΑ

SWITCHING CHARACTERISTICS

(At $T_A = +25$ °C, $V_S = \pm 2.5$ V, $C_L = 15$ pF $^{(2)}$, unless otherwise specified.)

PARAMETER	SYMBOL	CONDITIONS	TEMP	MIN	TYP	MAX	UNITS
Dropogotion Doloy (High to Low)		Overdrive = 10mV	+25°C		90		ns
Propagation Delay (High to Low)	t _{PHL}	Overdrive = 100mV	+25°C		60		ns
Dranagation Daloy (Low to Lligh)	t _{PLH}	Overdrive = 10mV	+25°C		90		ns
Propagation Delay (Low to High)		Overdrive = 100mV	+25°C		60		ns
Fall Time	t _{FALL}	Overdrive = 10mV	+25°C		20		ns
raii Tiille		Overdrive = 100mV	+25°C		20		ns
Rise Time	4	Overdrive = 10mV	+25°C		20		ns
Rise Time	t _{RISE}	Overdrive = 100mV	+25°C		20		ns

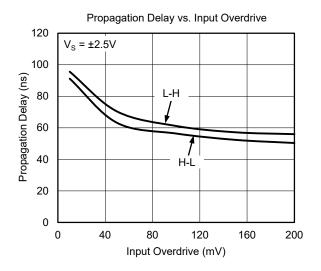
NOTES

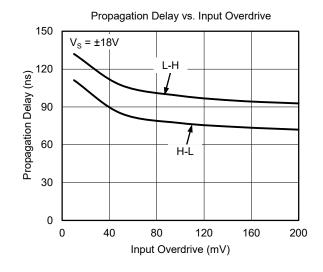
- 1. Any input voltage should not be lower than $(-V_S)$ 0.3V. The maximum input common mode voltage is $(+V_S)$ 1.5V, but it will not be damaged when the upper limit of the input voltage reaches 36V.
- 2. C_L: Load capacitance (jig and probe included).

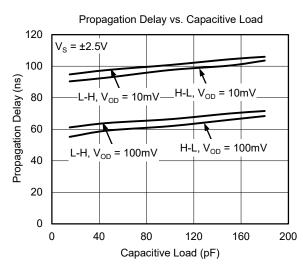


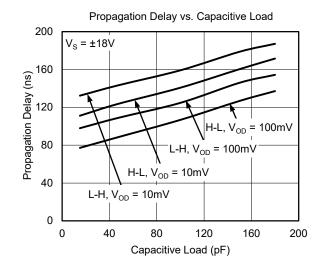
TYPICAL PERFORMANCE CHARACTERISTICS

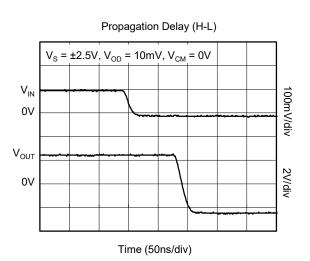
At $T_A = +25$ °C, $V_S = \pm 18$ V and $C_L = 15$ pF, unless otherwise noted.

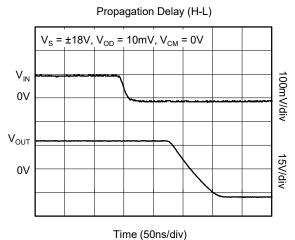






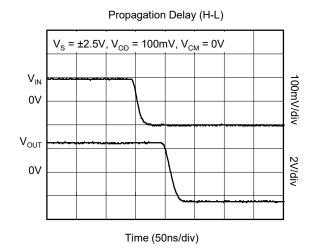


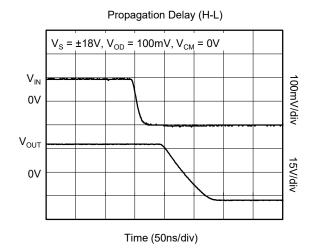


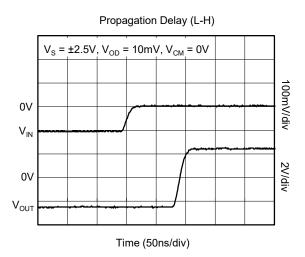


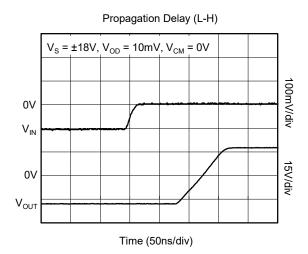
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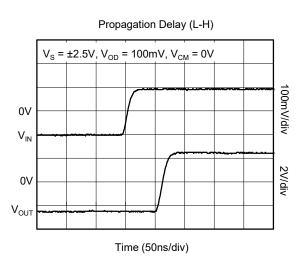
At T_A = +25°C, V_S = ±18V and C_L = 15pF, unless otherwise noted.

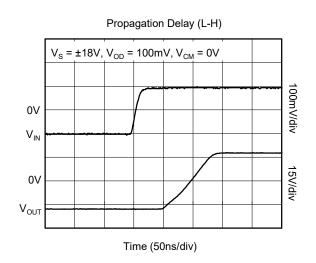






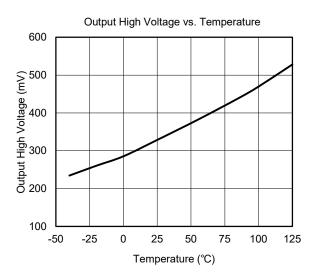


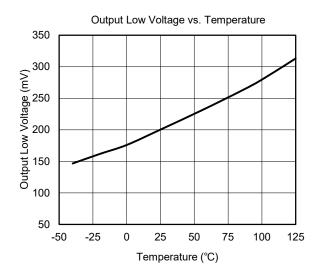


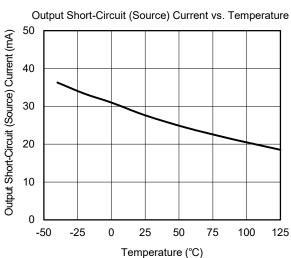


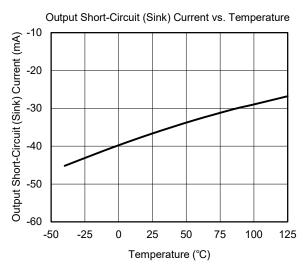
TYPICAL PERFORMANCE CHARACTERISTICS (continued)

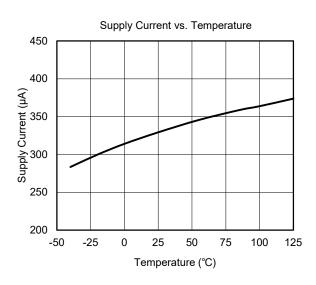
At $T_A = +25$ °C, $V_S = \pm 18$ V and $C_L = 15$ pF, unless otherwise noted.

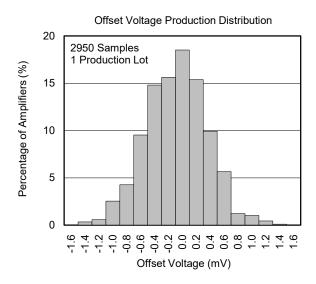












DETAILED DESCRIPTION

The SGM8773 is dual, high precision, low power comparator. The wide input voltage range and power supply range make the device a good choice for industrial equipment. Push-pull structure saves external pull-up resistors. The SGM8773 can be compatible with CMOS and TTL logics. For single-supply application, - V_S pin will be connected to GND.

Output Structure

In Figure 1, the SGM8773 has a push-pull output stage. When output is changed from logic high/low to low/high, the changed sink/source current pulls/pushes output pin to logic low/high. Beginning this transition, larger sink/source current is used to create a high slew rate transit from high/low to low/high. Once the output voltage reaches $V_{\text{OL}}/V_{\text{OH}}$, it will reduce the sink/source current to a just right value to maintain the $V_{\text{OL}}/V_{\text{OH}}$ static condition. This current-driven push-pull output stage will significantly reduce the power consumption in application system.

If low slew rate transition is needed in system design, adjusting the load capacitance will change the slew rate. The heavier capacitive load will slow down the output voltage transition. This feature will be used to reduce the interference generated by fast edge of transition between 1 and 0 in noise-sensitive system.

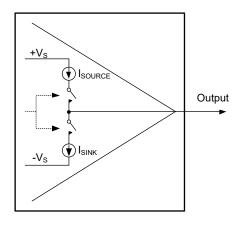


Figure 1. Push-Pull Output Structure

APPLICATION INFORMATION

Layout and Bypassing

Good power supply decoupling, layout and grounding are very important for SGM8773 to realize the full high-speed capabilities in system, following skills will be used:

 \bullet A 0.1µF to 4.7µF range ceramic capacitor is used to provide good power supply decoupling. This ceramic capacitor must be placed as close to +V_S pin as possible.

- For grounding, unbroken and low-inductance ground plane is a good choice.
- For Layout, use short PCB trace to avoid unwanted parasitic feedback around the comparator. SGM8773 must be soldered directly to the PCB and the socket is not recommended.

High Voltage, High Precision, Push-Pull, Dual Differential Comparator

SGM8773

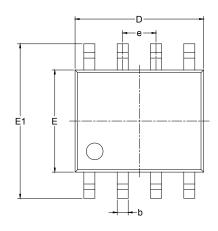
REVISION HISTORY

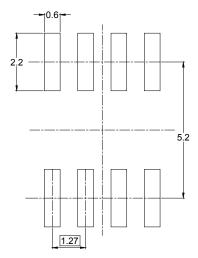
NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Original (DECEMBER 2018) to REV.A	Page
Changed from product preview to production data	All

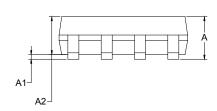


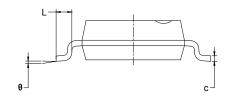
PACKAGE OUTLINE DIMENSIONS SOIC-8





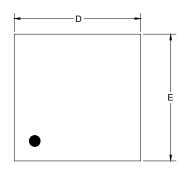
RECOMMENDED LAND PATTERN (Unit: mm)

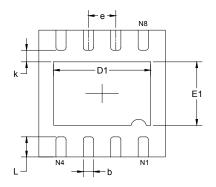




Symbol		nsions meters	Dimensions In Inches		
,	MIN MAX		MIN	MAX	
Α	1.350	1.750	0.053	0.069	
A1	0.100	0.250	0.004	0.010	
A2	1.350	1.550	0.053	0.061	
b	0.330	0.510	0.013	0.020	
С	0.170	0.250	0.006	0.010	
D	4.700	5.100	0.185	0.200	
E	3.800	4.000	0.150	0.157	
E1	5.800	6.200	0.228	0.244	
е	1.27	1.27 BSC		BSC	
L	0.400	1.270	0.016	0.050	
θ	0°	8°	0°	8°	

PACKAGE OUTLINE DIMENSIONS TDFN-3×3-8L

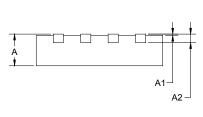




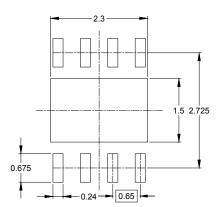
TOP VIEW







SIDE VIEW

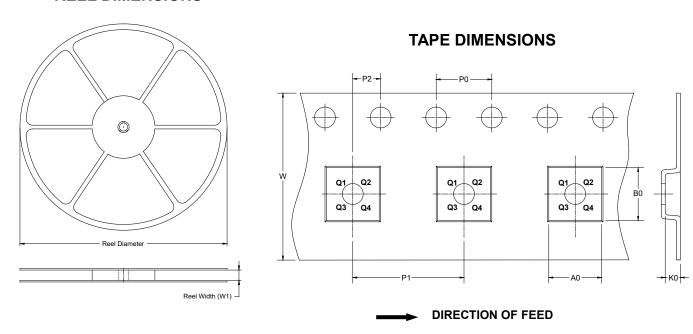


RECOMMENDED LAND PATTERN (Unit: mm)

Symbol	_	nsions meters	Dimensions In Inches		
	MIN MAX		MIN	MAX	
Α	0.700	0.800	0.028	0.031	
A1	0.000	0.050	0.000	0.002	
A2	0.203 REF 0.008 RE			REF	
D	2.900	3.100	0.114	0.122	
D1	2.200	2.400	0.087	0.094	
E	2.900	3.100	0.114	0.122	
E1	1.400	1.600	0.055	0.063	
k	0.200 MIN		0.008 MIN		
b	0.180	0.300	0.007	0.012	
е	0.650 TYP		0.026	TYP	
L	0.375	0.575	0.015 0.023		

TAPE AND REEL INFORMATION

REEL DIMENSIONS

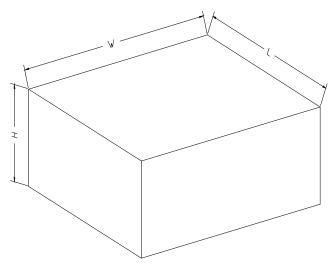


NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF TAPE AND REEL

Package Type	Reel Diameter	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	P1 (mm)	P2 (mm)	W (mm)	Pin1 Quadrant
SOIC-8	13"	12.4	6.40	5.40	2.10	4.0	8.0	2.0	12.0	Q1
TDFN-3×3-8L	13"	12.4	3.35	3.35	1.13	4.0	8.0	2.0	12.0	Q1

CARTON BOX DIMENSIONS



NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF CARTON BOX

Reel Type	Length (mm)	Width (mm)	Height (mm)	Pizza/Carton
13"	386	280	370	5